**ON Semiconductor** 

Is Now

# Onsemi

To learn more about onsemi<sup>™</sup>, please visit our website at <u>www.onsemi.com</u>

onsemi and ONSEMI. and other names, marks, and brands are registered and/or common law trademarks of Semiconductor Components Industries, LLC dba "onsemi" or its affiliates and/or subsidiaries in the United States and/or other countries. onsemi owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of onsemi product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. onsemi reserves the right to make changes at any time to any products or information herein, without notice. The information herein is provided "as-is" and onsemi makes no warranty, representation or guarantee regarding the accuracy of the information, product factures, availability, functionality, or suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using onsemi products, including compliance with all laws, regulations and asfety requirements or standards, regardless of any support or applications information provided by onsemi. "Typical" parameters which may be provided in onsemi data sheets and/or by customer's technical experts. onsemi products and actal performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. onsemi products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use onsemi products for any such unintended or unauthorized application, Buyer shall indemnify and hold onsemi and its officers, employees, subsidiari





\_\_\_\_\_

# September 2013

# File Number 2253.2

# N-Channel Power MOSFET 50V, 30A, 40 mΩ

This is an N-Channel enhancement mode silicon gate power field effect transistor designed for applications such as switching regulators, switching converters, motor drivers, relay drivers and drivers for high power bipolar switching transistors requiring high speed and low gate drive power. This type can be operated directly from integrated circuits.

Data Sheet

Formerly developmental type TA9771.

# **Ordering Information**

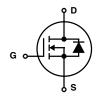
PART NUMBER	PACKAGE	BRAND
BUZ11-NR4941	TO-220AB	BUZ11

NOTE: When ordering, use the entire part number.

### Features

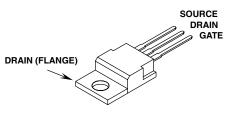
- 30A, 50V
- r<sub>DS(ON)</sub> = 0.040Ω
- SOA is Power Dissipation Limited
- Nanosecond Switching Speeds
- Linear Transfer Characteristics
- High Input Impedance
- Majority Carrier Device
- Related Literature
  - TB334 "Guidelines for Soldering Surface Mount Components to PC Boards"

# Symbol



# Packaging

JEDEC TO-220AB



#### Absolute Maximum Ratings $T_C = 25^{\circ}C$ , Unless Otherwise Specified

	BUZ11	UNITS
Drain to Source Breakdown Voltage (Note 1)V <sub>DS</sub>	50	V
Drain to Gate Voltage (R <sub>GS</sub> = 20kΩ) (Note 1) V <sub>DGR</sub>	50	V
Continuous Drain Current $T_C = 30^{\circ}CI_D$	30	Α
Pulsed Drain Current (Note 3)	120	А
Gate to Source VoltageV <sub>GS</sub>	±20	V
Maximum Power Dissipation	75	W
Linear Derating Factor	0.6	W/ <sup>o</sup> C
Operating and Storage Temperature	-55 to 150	°C
DIN Humidity Category - DIN 40040	E	
IEC Climatic Category - DIN IEC 68-1	55/150/56	
Maximum Temperature for Soldering		_
Leads at 0.063in (1.6mm) from Case for 10sTL	300	°C
Package Body for 10s, See Techbrief 334	260	°C

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

#### NOTE:

1.  $T_J = 25^{\circ}C$  to  $125^{\circ}C$ .

Electrical Specifications

 $T_C = 25^{\circ}C$ , Unless Otherwise Specified

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	ТҮР	MAX	UNITS
Drain to Source Breakdown Voltage	BV <sub>DSS</sub>	$I_{D} = 250 \mu A, V_{GS} = 0V$	50	-	-	V
Gate Threshold Voltage	V <sub>GS(TH)</sub>	$V_{GS} = V_{DS}$ , $I_D = 1mA$ (Figure 9)	2.1	3	4	V
Zero Gate Voltage Drain Current	IDSS	$T_J = 25^{o}C, V_{DS} = 50V, V_{GS} = 0V$	-	20	250	μA
		$T_{J} = 125^{o}C, V_{DS} = 50V, V_{GS} = 0V$	-	100	1000	μA
Gate to Source Leakage Current	I <sub>GSS</sub>	$V_{GS} = 20V, V_{DS} = 0V$	-	10	100	nA
Drain to Source On Resistance (Note 2)	rDS(ON)	I <sub>D</sub> = 15A, V <sub>GS</sub> = 10V (Figure 8)	-	0.03	0.04	Ω
Forward Transconductance (Note 2)	9fs	V <sub>DS</sub> = 25V, I <sub>D</sub> = 15A (Figure 11)	4	8	-	S
Turn-On Delay Time	t <sub>d(ON)</sub>	$V_{CC} = 30V, I_D \approx 3A, V_{GS} = 10V, R_{GS} = 50\Omega,$ $R_L = 10\Omega$	-	30	45	ns
Rise Time	t <sub>r</sub>		-	70	110	ns
Turn-Off Delay Time	t <sub>d(OFF)</sub>		-	180	230	ns
Fall Time	t <sub>f</sub>		-	130	170	ns
Input Capacitance	C <sub>ISS</sub>	$V_{DS} = 25V, V_{GS} = 0V, f = 1MHz$ (Figure 10)	-	1500	2000	pF
Output Capacitance	C <sub>OSS</sub>		-	750	1100	pF
Reverse Transfer Capacitance	C <sub>RSS</sub>		-	250	400	pF
Thermal Resistance Junction to Case	R <sub>θJC</sub>			≤ 1.67		°C/W
Thermal Resistance Junction to Ambient	R <sub>θJA</sub>			≤ 75		°C/W

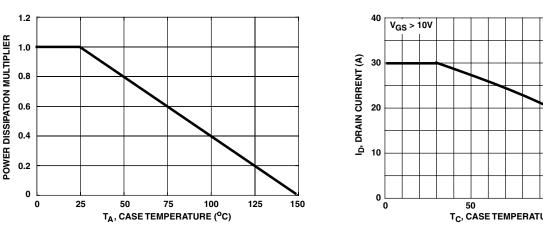
# Source to Drain Diode Specifications

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	ТҮР	MAX	UNITS
Continuous Source to Drain Current	I <sub>SD</sub>	$T_{C} = 25^{\circ}C$	-	-	30	А
Pulsed Source to Drain Current	I <sub>SDM</sub>	$T_{C} = 25^{\circ}C$	-	-	120	А
Source to Drain Diode Voltage	V <sub>SD</sub>	$T_{J} = 25^{o}C, I_{SD} = 60A, V_{GS} = 0V$	-	1.7	2.6	V
Reverse Recovery Time	t <sub>rr</sub>	$T_J = 25^{o}C$ , $I_{SD} = 30A$ , $dI_{SD}/dt = 100A/\mu s$ ,	-	200	-	ns
Reverse Recovery Charge	Q <sub>RR</sub>	V <sub>R</sub> = 30V	-	0.25	-	μC

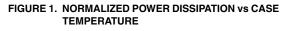
#### NOTES:

2. Pulse Test: Pulse width  $\leq$  300ms, duty cycle  $\leq$  2%.

3. Repetitive rating: pulse width limited by maximum junction temperature. See Transient Thermal Impedance curve (Figure 3).



# Typical Performance Curves Unless Otherwise Specified



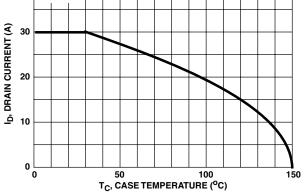
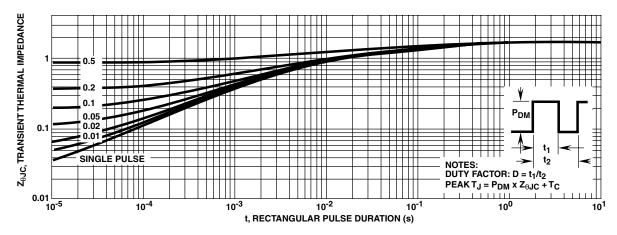


FIGURE 2. MAXIMUM CONTINUOUS DRAIN CURRENT vs **CASE TEMPERATURE** 





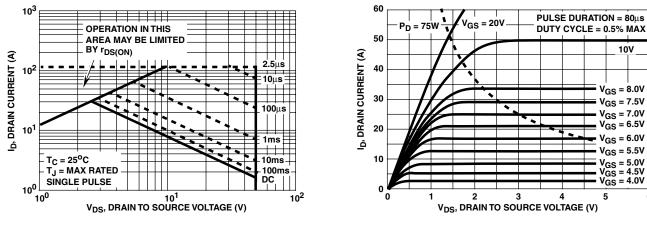
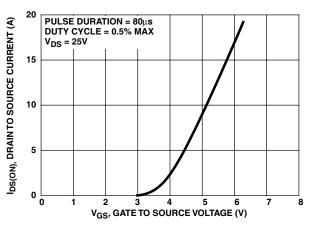


FIGURE 4. FORWARD BIAS SAFE OPERATING AREA

FIGURE 5. OUTPUT CHARACTERISTICS

6



# Typical Performance Curves Unless Otherwise Specified (Continued)



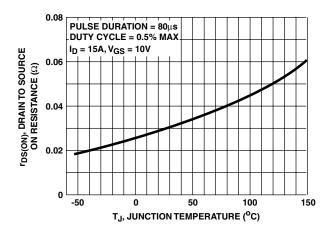


FIGURE 8. DRAIN TO SOURCE ON RESISTANCE vs JUNCTION TEMPERATURE

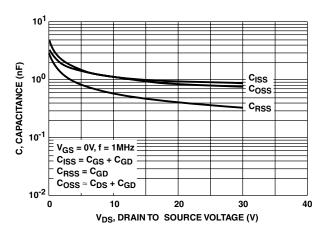


FIGURE 10. CAPACITANCE vs DRAIN TO SOURCE VOLTAGE

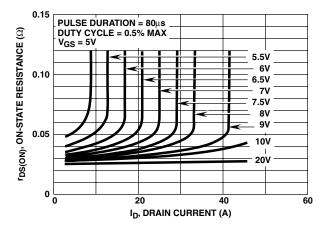


FIGURE 7. DRAIN TO SOURCE ON RESISTANCE vs GATE VOLTAGE AND DRAIN CURRENT

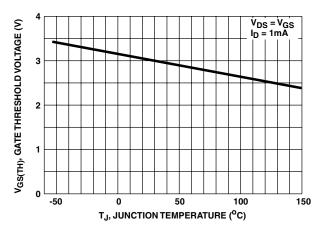
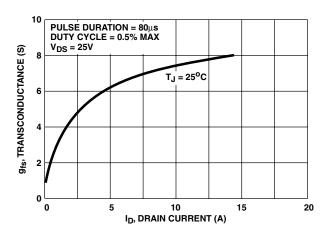
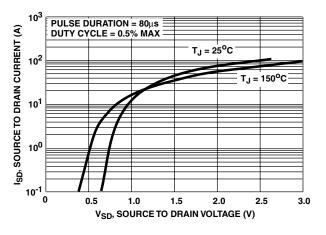


FIGURE 9. GATE THRESHOLD VOLTAGE vs JUNCTION TEMPERATURE







# Typical Performance Curves Unless Otherwise Specified (Continued)

FIGURE 12. SOURCE TO DRAIN DIODE VOLTAGE

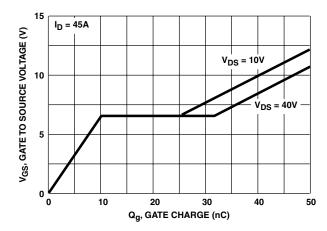


FIGURE 13. GATE TO SOURCE VOLTAGE vs GATE CHARGE

**Test Circuits and Waveforms** 

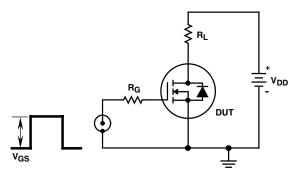


FIGURE 14. SWITCHING TIME TEST CIRCUIT

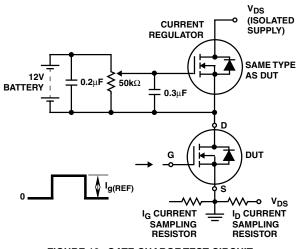


FIGURE 16. GATE CHARGE TEST CIRCUIT

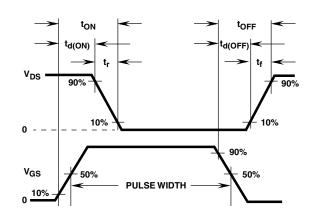


FIGURE 15. RESISTIVE SWITCHING WAVEFORMS

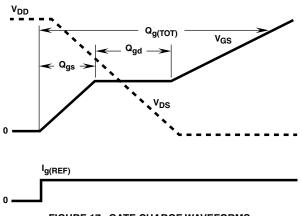


FIGURE 17. GATE CHARGE WAVEFORMS

www.onsemi.com 5

ON Semiconductor and are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at <u>www.onsemi.com/site/pdf/Patent-Marking.pdf</u>. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by ON Semiconductor "Typical" parameters which may be provided in ON Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights of others. ON Semiconductor products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor haves, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such uninten

#### PUBLICATION ORDERING INFORMATION

#### LITERATURE FULFILLMENT:

Literature Distribution Center for ON Semiconductor 19521 E. 32nd Pkwy, Aurora, Colorado 80011 USA Phone: 303-675-2175 or 800-344-3860 Toll Free USA/Canada Fax: 303-675-2176 or 800-344-3867 Toll Free USA/Canada Email: orderlit@onsemi.com N. American Technical Support: 800–282–9855 Toll Free USA/Canada Europe, Middle East and Africa Technical Support: Phone: 421 33 790 2910

Japan Customer Focus Center Phone: 81–3–5817–1050 ON Semiconductor Website: www.onsemi.com

Order Literature: http://www.onsemi.com/orderlit

For additional information, please contact your local Sales Representative

# **Mouser Electronics**

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

onsemi:

BUZ11-NR4941